

HAC RF Emissions Test Report

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Tested devices:	RM-820		
FCC ID:	PYARM-820	IC:	661V-RM820
Supplement reports:	T-Coil_RM-820_02, HAC_Photo_RM-820_03		
Testing has been carried out in accordance with:	ANSI C63.19-2007 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids		
Documentation:	The documentation of the testing performed on the tested devices is archived for 15 years at TCC Nokia.		
Test results:	The tested device complies with the requirements in respect of all parameters subject to the test. The test results and statements relate only to the items tested. The test report shall not be reproduced except in full, without written approval of the laboratory.		
Date and signatures:			
For the contents:			

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1. SUMMARY OF HAC RF EMISSION TEST REPORT

1.1 Test Details

Period of test	2012-07-03 to 2012-08-14
SN, HW, SW and DUT numbers of tested device	SN: 004402/13/870752/0, HW: 2003, SW: 1123.0005.8325.9680.139, DUT: 16349 SN: 004402/13/870734/8, HW: 2003, SW: 1123.0005.8325.9680.139, DUT: 16360 SN: 004402/13/870738/9, HW: 2003, SW: 1230.0035.9754.12312, DUT: 16347
Batteries used in testing	-
State of sample	Prototype unit
Notes	AWF = -5 for GSM, 0 for WCDMA

1.2 Maximum Results

The maximum measured HAC RF emissions values and categories for electric and magnetic fields are given in section 1.2.1 and 1.2.2 respectively.

1.2.1 Electric field measurements

Mode	Ch / Freq [MHz]	Conducted power	Limit of E-field max. value in category M3 [V/m]	Maximum E-field value after exclusion [V/m]	Category
GSM850	190 / 836.6	31.60 dBm	149.6 – 266.1	161.0	M3 (-5dB)
WCDMA850	4175 / 835.0	23.48 dBm	199.5 – 354.8	53.68	M4 (0dB)
WCDMA1700/2100	1312 / 1712.4	23.60 dBm	63.1 – 112.2	41.10	M4 (0dB)
GSM1900	512 / 1850.2	29.00 dBm	47.3 – 84.1	65.84	M3 (-5dB)
WCDMA1900	9538 / 1907.6	23.49 dBm	63.1 – 112.2	34.79	M4 (0dB)

1.2.2 Magnetic field measurements

Mode	Ch / Freq [MHz]	Conducted power	Limit of H-field max. value in category M3 [A/m]	Maximum H-field value after exclusion [A/m]	Category
GSM850	190 / 836.6	31.60 dBm	0.45 – 0.80	0.306	M4 (-5dB)
WCDMA850	4175 / 835.0	23.48 dBm	0.60 – 1.07	0.096	M4 (0dB)
WCDMA1700/2100	1312 / 1712.4	23.60 dBm	0.19 – 0.34	0.109	M4 (0dB)
GSM1900	810 / 1909.8	28.90 dBm	0.14 – 0.25	0.181	M3 (-5dB)
WCDMA1900	9400 / 1880.0	23.33 dBm	0.19 – 0.34	0.095	M4 (0dB)

1.2.3 Overall RF emissions category of the tested device

Mode	Combined category (E- and H-fields)	Pass / Fail
GSM850	M3	Pass
WCDMA850	M4	Pass
WCDMA1700/2100	M4	Pass
GSM1900	M3	Pass
WCDMA1900	M4	Pass
Final Category	M3	Pass

1.2.4 Maximum Drift

Maximum drift during measurements	0.30 dB
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1.2.5 Measurement Uncertainty

Extended Uncertainty (k=2) 95%, E-field	14.7 %
Extended Uncertainty (k=2) 95%, H-field	10.9 %

2. DESCRIPTION OF THE DEVICE UNDER TEST

Air-interface	Band (MHz)	Type	C63.19/ tested	Simultaneous Transmissions Note: not to be tested	Concurrent single transmission	Reduced power 20.19 (c) (1)	Voice Over Digital Transport (Data)
GSM	850	VO	Yes	Yes BT, WLAN	Yes: WCDMA Rated	No	NA
	1900				GPRS/EDGE, LTE Not rated	No	NA
	GPRS/EDGE	DT	NA	Yes BT, WLAN	Yes: * see note	NA*	YES
WCDMA	850 1700/2100 1900	V/D	Yes	Yes BT, WLAN	Yes: GSM Rated GPRS/EDGE, LTE Not rated	No	YES
LTE	700 (band 17) 850 (band 5) 1700/2100 (band 4) 1900 (band 2)	V/D	NA	Yes BT, WLAN	Yes: GSM, WCDMA Rated GPRS/EDGE, Not rated	NA*	YES
BT	2450	DT	NA	Yes GSM, GPRS/EDGE, WCDMA	NA*	NA*	NO
WLAN	2450	DT	NA	Yes GSM, GPRS/EDGE, WCDMA	NA*	NA*	YES
WLAN	5000	DT	NA	Yes GSM, GPRS/EDGE, WCDMA	NA*	NA*	YES

VO Voice CMRS/PSTN Service Only

V/D Voice CMRS/PSTN and Data Service

DT Digital Transport

*HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating.

Outside of USA and Canada, the transmitter of the device is capable of operating also in GSM/GPRS/EGPRS900, GSM/GPRS/EGPRS1800, WCDMA900 and WCDMA2100 bands which are not part of this filing.

2.1 Picture of Device

See separate report HAC_Photo_RM-820_03.

3. TEST CONDITIONS

3.1 Temperature and Humidity

Ambient temperature [°C]:	21.0 to 23.0
Ambient humidity [RH %]:	30 to 60

3.2 Test Signal, Frequencies, and Output Power

The transmitter of the device was put into operation by using a call tester. Communications between the device and the call tester were established by air link.

The device output power was set to maximum power level for all tests; a fully charged battery was used for every test sequence.

The transmission mode of the device in WCDMA HAC RF emission tests was configured to 12.2kbps RMC with all TPC bits set as “1”.

The measurements were performed on lowest, middle and highest channels.

The radiated output power of the device was measured by a separate test laboratory on the same unit as used for HAC testing. The results are given in the EMC report supporting this application.

4. DESCRIPTION OF THE TEST EQUIPMENT

4.1 Measurement system and components

The measurements were performed using an automated near-field scanning system, DASY5, manufactured by Schmid & Partner Engineering AG (SPEAG) in Switzerland.

The following table lists calibration dates of SPEAG components:

Test Equipment	Serial Number	Calibration interval	Calibration expiry
DAE 4	1316	12 months	2013-02
E-field Probe ER3DV6	2333	12 months	2013-04
H-field Probe H3DV6	6053	12 months	2013-04
Dipole Validation Kit, CD835V3	1004	24 months	2012-09
Dipole Validation Kit, CD1880V3	1003	24 months	2012-09
DASY52 software	Version 52.8	-	-

Additional test equipment used in testing and validation:

Test Equipment	Model	Serial Number	Calibration interval	Calibration expiry
Signal Generator	SML03	101264	2011-08	2012-08
Amplifier	ZHL-42-SMA	N072095-5	-	-
Power Meter	NRVD	840023/028	2011-08	2012-08
Power Sensor	URV5-Z2	839080/023	2011-08	2012-08
Call Tester	CMU 200	101111	-	-

4.1.1 Isotropic E-field probe ER3DV6

Construction	One dipole parallel, two dipoles normal to probe axis Built-in shielding against static charges PEEK enclosure material
Frequency	In air 100 MHz to >6 GHz; Linearity: ± 0.2 dB (100 MHz to 3 GHz)
Directivity	± 0.2 dB in air (rotation around probe axis) ± 0.4 dB in air (rotation normal to probe axis)
Dynamic Range	2 V/m to > 1000 V/m; Linearity: ± 0.2 dB
Dimensions	Overall length: 330 mm Tip length: 16 mm Body diameter: 12 mm Tip diameter: 8 mm
Application	Distance from probe tip to nearest point of dipole: 1.25 mm General near-field measurements up to 6 GHz Field component measurements Fast automatic scanning in phantoms

4.1.2 Isotropic H-field probe H3DV6

Construction	Three concentric loop sensors with 3.8 mm loop diameters Resistively loaded detector diodes for linear response Built-in shielding against static charges PEEK enclosure material
Frequency	200 MHz to 3 GHz; Output linearized (absolute accuracy $\pm 6.0\%$, $k=2$)
Directivity	± 0.25 dB (spherical isotropy error)
Dynamic Range	10 mA/m to 2 A/m at 1 GHz
Dimensions	Overall length: 330 mm Tip length: 40 mm Body diameter: 12 mm Tip diameter: 6 mm
Application	Distance from probe tip to nearest point of dipole: 1.1 mm General magnetic near-field measurements up to 3 GHz Field component measurements, surface current measurements Measurements in air or liquids, low interaction

4.1.3 Device Holder

The Device Holder and Test Arch are manufactured by Speag (www.speag.com). Test arch is used for all tests i.e. for both validation testing and device testing. The holder and test arch conforms to the requirements of ANSI C63.19.

The SPEAG device holder (see Section 5.1) was used to position the test device in all tests.

4.2 Validation of the System

The manufacturer calibrates the probes annually. Validation measurements are made regularly using the dipole validation kit. The power level used by manufacturer in dipole calibration is supplied to the dipole antenna. The antenna is scanned at 10mm distance between top surface of the dipole and calibration point of the probe.

System Validation, H-field and E-field

f [MHz]	Description	E-field [V/m]	H-field [A/m]
835	Reference result $\pm 10\%$ window	168.5 151.7 – 185.3	0.464 0.418 – 0.510
	2012-07-03	176.6	0.473
1880	Reference result $\pm 10\%$ window	135.1 121.6 – 148.6	0.458 0.412 – 0.504
	2012-07-03	123.0	0.433
	2012-08-14	134.3	0.432

Plots of the system validation scans are given in Appendix A.

5. DESCRIPTION OF THE TEST PROCEDURE

5.1 Test Arch and Device Holder

The test device was placed in the Device Holder (illustrated below) that is supplied by SPEAG. Using this positioner the tested device is positioned under Test Arch.



Device holder and Test Arch supplied by SPEAG

5.2 Test Positions

5.2.1 Scan area centered at the acoustic output

The device was positioned such that Device Reference plane was touching the bottom of the Test Arch. The scan is centered at the acoustic output by aligning the acoustic output with the intersection of the Test Arch's middle bar and dielectric wire.

5.3 Scan Procedures

Near field scans of 5cm x 5cm were used for determination of the field distribution. Measurement plane distance from WD reference plane is 15mm. Scans were performed for both E- and H-field using appropriate probe. DASY software divides detected values into 3 x 3 sub grids as described in the C63.19 standard.

5.4 Probe Modulation Factor

All raw measurements in DASY52 system are presented as RMS values. The measurement software then applies Probe Modulation Factor (PMF) to convert readings to “slot averaged” peak values as required by C63.19 standard. Modulation specific PMF values are included in the probe calibration parameters.

5.5 Sub-grid Exclusion

The measurement grid defined in C63.19 consists of 9 evenly sized blocks, which are used to define permissible exclusion areas. For both E- and H-field measurements three contiguous blocks may be excluded from the measurements except the center block may never be excluded. There must be 4 blocks left that are common for both E- and H-field measurements, so maximum of 5 different blocks can be excluded.

5.6 Category Limits

From remaining maximum values after exclusion process, Hearing Aid M-category is defined according to the category limits of C63.19 – 2007.

		Limits for RF-parameters <960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	631.0 to 1122.0	1.91 to 3.39
	-5	473.2 to 841.4	1.43 to 2.54
M2	0	354.8 to 631.0	1.07 to 1.91
	-5	266.1 to 473.2	0.80 to 1.43
M3	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M4	0	<199.5	<0.60
	-5	<149.6	<0.45

		Limits for RF-parameters >960MHz	
Category	AWF [dB]	E-field [V/m]	H-field [A/m]
M1	0	199.5 to 354.8	0.60 to 1.07
	-5	149.6 to 266.1	0.45 to 0.80
M2	0	112.2 to 199.5	0.34 to 0.60
	-5	84.1 to 149.6	0.25 to 0.45
M3	0	63.1 to 112.2	0.19 to 0.34
	-5	47.3 to 84.1	0.14 to 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.14

6. MEASUREMENT UNCERTAINTY

Source of Uncertainty	Tolerance ±%	Prob. Dist.	Div.	ci E	ci H	Standard Uncertainty ±%, E	Standard Uncertainty ±%, H	Remark
MEASUREMENT SYSTEM								
Probe Calibration	5.1	N	1	1	1	5.1	5.1	
Axial Isotropy	4.7	R	√3	1	1	2.7	2.7	
Sensor Displacement	16.5	R	√3	1	0.145	9.5	1.4	
Boundary Effect	2.4	R	√3	1	1	1.4	1.4	
Linearity	4.7	R	√3	1	1	2.7	2.7	SAR
Scaling to Peak Envelope Power	2.0	R	√3	1	1	1.2	1.2	
System Detection Limit	1.0	R	√3	1	1	0.6	0.6	
Readout Electronics	0.3	N	1	1	1	0.3	0.3	SAR
Response Time	0.8	R	√3	1	1	0.5	0.5	
Integration Time	2.6	R	√3	1	1	1.5	1.5	SAR
RF Ambient Conditions	3.0	R	√3	1	1	1.7	1.7	SAR
RF Reflections	12.0	R	√3	1	1	6.9	6.9	
Probe Positioner	1.2	R	√3	1	0.67	0.7	0.5	
Probe Positioning	4.7	R	√3	1	0.67	2.7	1.8	
Extrapolation and Interpolation	1.0	R	√3	1	1	0.6	0.6	SAR
TEST SAMPLE RELATED								
Device Positioning Vertical	4.7	R	√3	1	0.67	2.7	1.8	
Device Positioning Lateral	1.0	R	√3	1	1	0.6	0.6	
Device Holder and Test Arch	2.4	R	√3	1	1	1.4	1.4	
Power Drift	5.0	R	√3	1	1	2.9	2.9	SAR
TEST ARCH AND SETUP RELATED								
Test Arch Thickness	2.4	R	√3	1	0.67	1.4	0.9	
Combined Standard Uncertainty						14.7	10.9	
Expanded Uncertainty on Power						29.4	21.8	
Expanded Uncertainty on Field						14.7	10.9	

7. RESULTS

The calculated maximum field values for the test device are tabulated below:

GSM850, RF emissions results

Mode	Test configuration	Ch 128 824.2 MHz	Ch 190 836.6 MHz	Ch 251 848.8 MHz
GSM850	Power	31.60 dBm	31.60 dBm	31.80 dBm
	E-field [V/m]	116.6	161.0	133.0
	H-field [A/m]	0.214	0.306	0.249
	Category	M4 (-5 dB)	M3 (-5 dB)	M4 (-5 dB)

WCDMA850, RF emissions results

Mode	Test configuration	Ch 4132 826.4 MHz	Ch 4175 835.0 MHz	Ch 4233 846.6 MHz
WCDMA850	Power	23.93 dBm	23.48 dBm	23.94 dBm
	E-field [V/m]	49.82	53.68	50.97
	H-field [A/m]	0.088	0.096	0.087
	Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

WCDMA1700/2100, RF emissions results

Mode	Test configuration	Ch 1312 1712.4 MHz	Ch 1412 1732.4 MHz	Ch 1513 1752.6 MHz
WCDMA 1700/2100	Power	23.60 dBm	23.40 dBm	23.50 dBm
	E-field [V/m]	41.10	39.61	37.65
	H-field [A/m]	0.109	0.106	0.096
	Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

GSM1900, RF emissions results

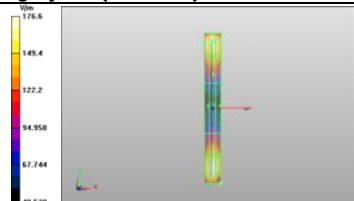
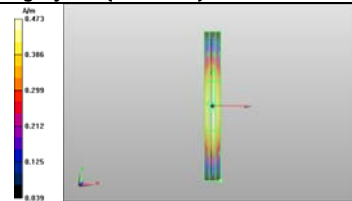
Mode	Test configuration	Ch 512 1850.2MHz	Ch 661 1880.0MHz	Ch 810 1909.8MHz
GSM1900	Power	29.00 dBm	28.90 dBm	28.90 dBm
	E-field [V/m]	65.84	59.09	64.87
	H-field [A/m]	0.169	0.162	0.181
	Category	M3 (-5 dB)	M3 (-5 dB)	M3 (-5 dB)

WCDMA1900, RF emissions results

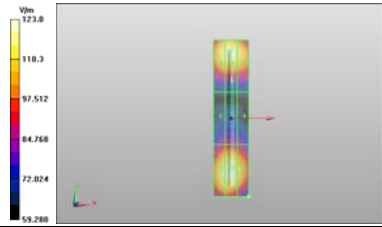
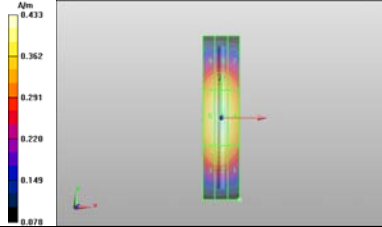
Mode	Test configuration	Ch 9262 1852.4MHz	Ch 9400 1880.0MHz	Ch 9538 1907.6MHz
WCDMA1900	Power	23.44 dBm	23.33 dBm	23.49 dBm
	E-field [V/m]	32.66	31.42	34.79
	H-field [A/m]	0.094	0.095	0.095
	Category	M4 (0 dB)	M4 (0 dB)	M4 (0 dB)

Plots of the measurement scans are shown in **Appendix B**. Excluded cells are colored orange.

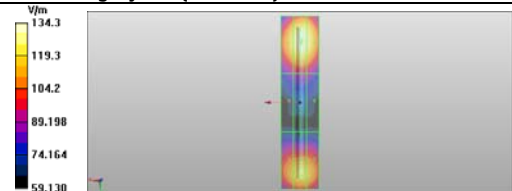
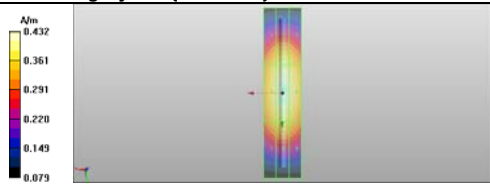
APPENDIX A: SYSTEM VALIDATION SCANS

SYSTEM VALIDATION DATA 850MHZ										
Date/Time: 2012-07-03 09:51:20 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1004					Date/Time: 2012-07-03 10:30:14 Test Laboratory: TCC Nokia Type: CD835V3; Serial: 1004					
Communication System: CW Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m ³ Phantom section: RF Section DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)					Communication System: CW Frequency: 835 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m ³ Phantom section: RF Section DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)					
Dipole E-Field measurement 835MHz/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 113.9 V/m; Power Drift = -0.02 dB PMF = 1.000 is applied. E-field emissions = 176.6 V/m Near-field category: M4 (AWF 0 dB)					Dipole H-Field meaurement 835MHz/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.4970 A/m; Power Drift = 0.01 dB PMR not calibrated. PMF = 1.000 is applied. H-field emissions = 0.4726 A/m Near-field category: M4 (AWF 0 dB)					
										
Grid 1 M4 168.9 V/m			Grid 2 M4 176.6 V/m		Grid 3 M4 170.6 V/m					
Grid 4 M4 92.81 V/m			Grid 5 M4 96.21 V/m		Grid 6 M4 93.55 V/m					
Grid 7 M4 166.3 V/m			Grid 8 M4 171.9 V/m		Grid 9 M4 167.7 V/m					
Grid 1 M4 0.404 A/m			Grid 2 M4 0.429 A/m		Grid 3 M4 0.412 A/m					
Grid 4 M4 0.444 A/m			Grid 5 M4 0.473 A/m		Grid 6 M4 0.454 A/m					
Grid 7 M4 0.385 A/m			Grid 8 M4 0.409 A/m		Grid 9 M4 0.394 A/m					

SYSTEM VALIDATION DATA 1900MHZ

Date/Time: 2012-07-03 10:06:17 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1003				Date/Time: 2012-07-03 10:19:12 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1003			
Communication System: CW Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)				Communication System: CW Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)			
Dipole E-Field measurement 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 136.5 V/m; Power Drift = 0.00 dB PMF = 1.000 is applied. E-field emissions = 123.0 V/m Near-field category: M2 (AWF 0 dB)				Dipole H-Field measurement 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.4570 A/m; Power Drift = -0.01 dB PMF = 1.000 is applied. H-field emissions = 0.4325 A/m Near-field category: M2 (AWF 0 dB)			
							
Grid 1 M2	Grid 2 M2	Grid 3 M2		Grid 1 M2	Grid 2 M2	Grid 3 M2	
116.0 V/m	123.0 V/m	121.9 V/m		0.366 A/m	0.390 A/m	0.380 A/m	
Grid 4 M3	Grid 5 M3	Grid 6 M3		Grid 4 M2	Grid 5 M2	Grid 6 M2	
86.77 V/m	90.20 V/m	88.42 V/m		0.406 A/m	0.433 A/m	0.420 A/m	
Grid 7 M2	Grid 8 M2	Grid 9 M2		Grid 7 M2	Grid 8 M2	Grid 9 M2	
117.3 V/m	122.3 V/m	120.3 V/m		0.364 A/m	0.384 A/m	0.372 A/m	

SYSTEM VALIDATION DATA 1900MHz

Date/Time: 2012-08-14 07:54:09 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1003 Communication System: CW Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	Date/Time: 2012-08-14 08:05:08 Test Laboratory: TCC Nokia Type: CD1880V3; Serial: 1003 Communication System: CW Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: Not Specified - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																																				
Dipole E-Field measurement 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 135.5 V/m; Power Drift = 0.00 dB PMR not calibrated. PMF = 1.000 is applied. E-field emissions = 134.3 V/m Near-field category: M2 (AWF 0 dB)	Dipole H-Field measurement 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.4560 A/m; Power Drift = -0.02 dB PMR not calibrated. PMF = 1.000 is applied. H-field emissions = 0.4322 A/m Near-field category: M2 (AWF 0 dB)																																				
																																					
<table><tr><td>Grid 1 M2</td><td>Grid 2 M2</td><td>Grid 3 M2</td></tr><tr><td>126.2 V/m</td><td>134.3 V/m</td><td>131.7 V/m</td></tr><tr><td>Grid 4 M3</td><td>Grid 5 M3</td><td>Grid 6 M3</td></tr><tr><td>88.37 V/m</td><td>92.67 V/m</td><td>90.17 V/m</td></tr><tr><td>Grid 7 M2</td><td>Grid 8 M2</td><td>Grid 9 M2</td></tr><tr><td>117.5 V/m</td><td>122.7 V/m</td><td>121.5 V/m</td></tr></table>	Grid 1 M2	Grid 2 M2	Grid 3 M2	126.2 V/m	134.3 V/m	131.7 V/m	Grid 4 M3	Grid 5 M3	Grid 6 M3	88.37 V/m	92.67 V/m	90.17 V/m	Grid 7 M2	Grid 8 M2	Grid 9 M2	117.5 V/m	122.7 V/m	121.5 V/m	<table><tr><td>Grid 1 M2</td><td>Grid 2 M2</td><td>Grid 3 M2</td></tr><tr><td>0.376 A/m</td><td>0.399 A/m</td><td>0.384 A/m</td></tr><tr><td>Grid 4 M2</td><td>Grid 5 M2</td><td>Grid 6 M2</td></tr><tr><td>0.410 A/m</td><td>0.432 A/m</td><td>0.418 A/m</td></tr><tr><td>Grid 7 M2</td><td>Grid 8 M2</td><td>Grid 9 M2</td></tr><tr><td>0.360 A/m</td><td>0.377 A/m</td><td>0.365 A/m</td></tr></table>	Grid 1 M2	Grid 2 M2	Grid 3 M2	0.376 A/m	0.399 A/m	0.384 A/m	Grid 4 M2	Grid 5 M2	Grid 6 M2	0.410 A/m	0.432 A/m	0.418 A/m	Grid 7 M2	Grid 8 M2	Grid 9 M2	0.360 A/m	0.377 A/m	0.365 A/m
Grid 1 M2	Grid 2 M2	Grid 3 M2																																			
126.2 V/m	134.3 V/m	131.7 V/m																																			
Grid 4 M3	Grid 5 M3	Grid 6 M3																																			
88.37 V/m	92.67 V/m	90.17 V/m																																			
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0.376 A/m	0.399 A/m	0.384 A/m																																			
Grid 4 M2	Grid 5 M2	Grid 6 M2																																			
0.410 A/m	0.432 A/m	0.418 A/m																																			
Grid 7 M2	Grid 8 M2	Grid 9 M2																																			
0.360 A/m	0.377 A/m	0.365 A/m																																			

APPENDIX B: MEASUREMENT SCANS

MEASUREMENT DATA GSM850, CHANNEL LOW (824.2 MHz)

Date/Time: 2012-07-05 10:04:23 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 824.2 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 11:59:48 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 824.2 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe/E Scan - GSM850 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 47.35 V/m; Power Drift = 0.04 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 116.6 V/m Near-field category: M4 (AWF -5 dB)	Device H-Field measurement with H3DV6 probe/H Scan - GSM850 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.05400 A/m; Power Drift = -0.02 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.2136 A/m Near-field category: M4 (AWF -5 dB)																		
<table><tr><td>Grid 1 M4 109.4 V/m</td><td>Grid 2 M4 118.7 V/m</td><td>Grid 3 M4 117.0 V/m</td></tr><tr><td>Grid 4 M4 102.0 V/m</td><td>Grid 5 M4 116.6 V/m</td><td>Grid 6 M4 115.5 V/m</td></tr><tr><td>Grid 7 M4 97.58 V/m</td><td>Grid 8 M4 113.0 V/m</td><td>Grid 9 M4 112.2 V/m</td></tr></table>	Grid 1 M4 109.4 V/m	Grid 2 M4 118.7 V/m	Grid 3 M4 117.0 V/m	Grid 4 M4 102.0 V/m	Grid 5 M4 116.6 V/m	Grid 6 M4 115.5 V/m	Grid 7 M4 97.58 V/m	Grid 8 M4 113.0 V/m	Grid 9 M4 112.2 V/m	<table><tr><td>Grid 1 M4 0.263 A/m</td><td>Grid 2 M4 0.195 A/m</td><td>Grid 3 M4 0.123 A/m</td></tr><tr><td>Grid 4 M4 0.259 A/m</td><td>Grid 5 M4 0.196 A/m</td><td>Grid 6 M4 0.129 A/m</td></tr><tr><td>Grid 7 M4 0.283 A/m</td><td>Grid 8 M4 0.214 A/m</td><td>Grid 9 M4 0.140 A/m</td></tr></table>	Grid 1 M4 0.263 A/m	Grid 2 M4 0.195 A/m	Grid 3 M4 0.123 A/m	Grid 4 M4 0.259 A/m	Grid 5 M4 0.196 A/m	Grid 6 M4 0.129 A/m	Grid 7 M4 0.283 A/m	Grid 8 M4 0.214 A/m	Grid 9 M4 0.140 A/m
Grid 1 M4 109.4 V/m	Grid 2 M4 118.7 V/m	Grid 3 M4 117.0 V/m																	
Grid 4 M4 102.0 V/m	Grid 5 M4 116.6 V/m	Grid 6 M4 115.5 V/m																	
Grid 7 M4 97.58 V/m	Grid 8 M4 113.0 V/m	Grid 9 M4 112.2 V/m																	
Grid 1 M4 0.263 A/m	Grid 2 M4 0.195 A/m	Grid 3 M4 0.123 A/m																	
Grid 4 M4 0.259 A/m	Grid 5 M4 0.196 A/m	Grid 6 M4 0.129 A/m																	
Grid 7 M4 0.283 A/m	Grid 8 M4 0.214 A/m	Grid 9 M4 0.140 A/m																	
dB 0 -2.53 -5.05 -7.58 -10.10 -12.63																			

MEASUREMENT DATA GSM850, CHANNEL MIDDLE (836.6 MHz)

Date/Time: 2012-07-05 09:59:05 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 836.6 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 11:54:45 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 836.6 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe/E Scan - GSM850 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 66.84 V/m; Power Drift = -0.08 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 161.0 V/m Near-field category: M3 (AWF -5 dB)	Device H-Field measurement with H3DV6 probe/H Scan - GSM850 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.08200 A/m; Power Drift = 0.30 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.3061 A/m Near-field category: M4 (AWF -5 dB)																		
<table><tr><td>Grid 1 M4 146.4 V/m</td><td>Grid 2 M3 162.8 V/m</td><td>Grid 3 M3 159.8 V/m</td></tr><tr><td>Grid 4 M4 142.3 V/m</td><td>Grid 5 M3 161.0 V/m</td><td>Grid 6 M3 159.4 V/m</td></tr><tr><td>Grid 7 M4 138.0 V/m</td><td>Grid 8 M3 156.5 V/m</td><td>Grid 9 M3 155.0 V/m</td></tr></table>	Grid 1 M4 146.4 V/m	Grid 2 M3 162.8 V/m	Grid 3 M3 159.8 V/m	Grid 4 M4 142.3 V/m	Grid 5 M3 161.0 V/m	Grid 6 M3 159.4 V/m	Grid 7 M4 138.0 V/m	Grid 8 M3 156.5 V/m	Grid 9 M3 155.0 V/m	<table><tr><td>Grid 1 M4 0.394 A/m</td><td>Grid 2 M4 0.294 A/m</td><td>Grid 3 M4 0.195 A/m</td></tr><tr><td>Grid 4 M4 0.380 A/m</td><td>Grid 5 M4 0.291 A/m</td><td>Grid 6 M4 0.203 A/m</td></tr><tr><td>Grid 7 M4 0.401 A/m</td><td>Grid 8 M4 0.306 A/m</td><td>Grid 9 M4 0.211 A/m</td></tr></table>	Grid 1 M4 0.394 A/m	Grid 2 M4 0.294 A/m	Grid 3 M4 0.195 A/m	Grid 4 M4 0.380 A/m	Grid 5 M4 0.291 A/m	Grid 6 M4 0.203 A/m	Grid 7 M4 0.401 A/m	Grid 8 M4 0.306 A/m	Grid 9 M4 0.211 A/m
Grid 1 M4 146.4 V/m	Grid 2 M3 162.8 V/m	Grid 3 M3 159.8 V/m																	
Grid 4 M4 142.3 V/m	Grid 5 M3 161.0 V/m	Grid 6 M3 159.4 V/m																	
Grid 7 M4 138.0 V/m	Grid 8 M3 156.5 V/m	Grid 9 M3 155.0 V/m																	
Grid 1 M4 0.394 A/m	Grid 2 M4 0.294 A/m	Grid 3 M4 0.195 A/m																	
Grid 4 M4 0.380 A/m	Grid 5 M4 0.291 A/m	Grid 6 M4 0.203 A/m																	
Grid 7 M4 0.401 A/m	Grid 8 M4 0.306 A/m	Grid 9 M4 0.211 A/m																	
dB 0 -2.12 -4.24 -6.35 -8.47 -10.59																			

MEASUREMENT DATA GSM850, CHANNEL HIGH (848.8 MHz)

Date/Time: 2012-07-05 10:09:33 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 848.8 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:05:12 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 848.8 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe/E Scan - GSM850 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 53.94 V/m; Power Drift = 0.00 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 133.0 V/m Near-field category: M4 (AWF -5 dB)	Device H-Field measurement with H3DV6 probe/H Scan - GSM850 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.06400 A/m; Power Drift = -0.03 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.2492 A/m Near-field category: M4 (AWF -5 dB)																		
<table><tr><td>Grid 1 M4 114.2 V/m</td><td>Grid 2 M4 133.0 V/m</td><td>Grid 3 M4 132.7 V/m</td></tr><tr><td>Grid 4 M4 111.0 V/m</td><td>Grid 5 M4 133.0 V/m</td><td>Grid 6 M4 132.6 V/m</td></tr><tr><td>Grid 7 M4 108.0 V/m</td><td>Grid 8 M4 130.4 V/m</td><td>Grid 9 M4 130.2 V/m</td></tr></table>	Grid 1 M4 114.2 V/m	Grid 2 M4 133.0 V/m	Grid 3 M4 132.7 V/m	Grid 4 M4 111.0 V/m	Grid 5 M4 133.0 V/m	Grid 6 M4 132.6 V/m	Grid 7 M4 108.0 V/m	Grid 8 M4 130.4 V/m	Grid 9 M4 130.2 V/m	<table><tr><td>Grid 1 M4 0.327 A/m</td><td>Grid 2 M4 0.249 A/m</td><td>Grid 3 M4 0.159 A/m</td></tr><tr><td>Grid 4 M4 0.301 A/m</td><td>Grid 5 M4 0.229 A/m</td><td>Grid 6 M4 0.154 A/m</td></tr><tr><td>Grid 7 M4 0.318 A/m</td><td>Grid 8 M4 0.246 A/m</td><td>Grid 9 M4 0.169 A/m</td></tr></table>	Grid 1 M4 0.327 A/m	Grid 2 M4 0.249 A/m	Grid 3 M4 0.159 A/m	Grid 4 M4 0.301 A/m	Grid 5 M4 0.229 A/m	Grid 6 M4 0.154 A/m	Grid 7 M4 0.318 A/m	Grid 8 M4 0.246 A/m	Grid 9 M4 0.169 A/m
Grid 1 M4 114.2 V/m	Grid 2 M4 133.0 V/m	Grid 3 M4 132.7 V/m																	
Grid 4 M4 111.0 V/m	Grid 5 M4 133.0 V/m	Grid 6 M4 132.6 V/m																	
Grid 7 M4 108.0 V/m	Grid 8 M4 130.4 V/m	Grid 9 M4 130.2 V/m																	
Grid 1 M4 0.327 A/m	Grid 2 M4 0.249 A/m	Grid 3 M4 0.159 A/m																	
Grid 4 M4 0.301 A/m	Grid 5 M4 0.229 A/m	Grid 6 M4 0.154 A/m																	
Grid 7 M4 0.318 A/m	Grid 8 M4 0.246 A/m	Grid 9 M4 0.169 A/m																	
dB 0 -2.16 -4.31 -6.47 -8.62 -10.78																			

MEASUREMENT DATA WCDMA850, CHANNEL LOW (826.4 MHz)

Date/Time: 2012-07-03 13:44:53 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 826.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:53:14 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 826.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA5 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 58.55 V/m; Power Drift = -0.03 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 49.82 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA5 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.06700 A/m; Power Drift = -0.03 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.08818 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 46.59 V/m</td><td>Grid 2 M4 50.84 V/m</td><td>Grid 3 M4 49.87 V/m</td></tr><tr><td>Grid 4 M4 43.93 V/m</td><td>Grid 5 M4 49.82 V/m</td><td>Grid 6 M4 49.36 V/m</td></tr><tr><td>Grid 7 M4 41.65 V/m</td><td>Grid 8 M4 48.04 V/m</td><td>Grid 9 M4 47.64 V/m</td></tr></table>	Grid 1 M4 46.59 V/m	Grid 2 M4 50.84 V/m	Grid 3 M4 49.87 V/m	Grid 4 M4 43.93 V/m	Grid 5 M4 49.82 V/m	Grid 6 M4 49.36 V/m	Grid 7 M4 41.65 V/m	Grid 8 M4 48.04 V/m	Grid 9 M4 47.64 V/m	<table><tr><td>Grid 1 M4 0.111 A/m</td><td>Grid 2 M4 0.080 A/m</td><td>Grid 3 M4 0.050 A/m</td></tr><tr><td>Grid 4 M4 0.106 A/m</td><td>Grid 5 M4 0.082 A/m</td><td>Grid 6 M4 0.055 A/m</td></tr><tr><td>Grid 7 M4 0.114 A/m</td><td>Grid 8 M4 0.088 A/m</td><td>Grid 9 M4 0.060 A/m</td></tr></table>	Grid 1 M4 0.111 A/m	Grid 2 M4 0.080 A/m	Grid 3 M4 0.050 A/m	Grid 4 M4 0.106 A/m	Grid 5 M4 0.082 A/m	Grid 6 M4 0.055 A/m	Grid 7 M4 0.114 A/m	Grid 8 M4 0.088 A/m	Grid 9 M4 0.060 A/m
Grid 1 M4 46.59 V/m	Grid 2 M4 50.84 V/m	Grid 3 M4 49.87 V/m																	
Grid 4 M4 43.93 V/m	Grid 5 M4 49.82 V/m	Grid 6 M4 49.36 V/m																	
Grid 7 M4 41.65 V/m	Grid 8 M4 48.04 V/m	Grid 9 M4 47.64 V/m																	
Grid 1 M4 0.111 A/m	Grid 2 M4 0.080 A/m	Grid 3 M4 0.050 A/m																	
Grid 4 M4 0.106 A/m	Grid 5 M4 0.082 A/m	Grid 6 M4 0.055 A/m																	
Grid 7 M4 0.114 A/m	Grid 8 M4 0.088 A/m	Grid 9 M4 0.060 A/m																	
dB 0 -2.43 -4.87 -7.30 -9.74 -12.17																			

MEASUREMENT DATA WCDMA850, CHANNEL MIDDLE (835 MHz)

Date/Time: 2012-07-03 13:37:55 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 835 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:47:58 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 835 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA5 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 63.24 V/m; Power Drift = -0.02 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 53.68 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA5 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.07400 A/m; Power Drift = 0.10 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.09567 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 50.62 V/m</td><td>Grid 2 M4 55.68 V/m</td><td>Grid 3 M4 53.70 V/m</td></tr><tr><td>Grid 4 M4 47.69 V/m</td><td>Grid 5 M4 53.68 V/m</td><td>Grid 6 M4 52.90 V/m</td></tr><tr><td>Grid 7 M4 44.88 V/m</td><td>Grid 8 M4 50.96 V/m</td><td>Grid 9 M4 50.32 V/m</td></tr></table>	Grid 1 M4 50.62 V/m	Grid 2 M4 55.68 V/m	Grid 3 M4 53.70 V/m	Grid 4 M4 47.69 V/m	Grid 5 M4 53.68 V/m	Grid 6 M4 52.90 V/m	Grid 7 M4 44.88 V/m	Grid 8 M4 50.96 V/m	Grid 9 M4 50.32 V/m	<table><tr><td>Grid 1 M4 0.123 A/m</td><td>Grid 2 M4 0.090 A/m</td><td>Grid 3 M4 0.057 A/m</td></tr><tr><td>Grid 4 M4 0.116 A/m</td><td>Grid 5 M4 0.091 A/m</td><td>Grid 6 M4 0.061 A/m</td></tr><tr><td>Grid 7 M4 0.122 A/m</td><td>Grid 8 M4 0.096 A/m</td><td>Grid 9 M4 0.065 A/m</td></tr></table>	Grid 1 M4 0.123 A/m	Grid 2 M4 0.090 A/m	Grid 3 M4 0.057 A/m	Grid 4 M4 0.116 A/m	Grid 5 M4 0.091 A/m	Grid 6 M4 0.061 A/m	Grid 7 M4 0.122 A/m	Grid 8 M4 0.096 A/m	Grid 9 M4 0.065 A/m
Grid 1 M4 50.62 V/m	Grid 2 M4 55.68 V/m	Grid 3 M4 53.70 V/m																	
Grid 4 M4 47.69 V/m	Grid 5 M4 53.68 V/m	Grid 6 M4 52.90 V/m																	
Grid 7 M4 44.88 V/m	Grid 8 M4 50.96 V/m	Grid 9 M4 50.32 V/m																	
Grid 1 M4 0.123 A/m	Grid 2 M4 0.090 A/m	Grid 3 M4 0.057 A/m																	
Grid 4 M4 0.116 A/m	Grid 5 M4 0.091 A/m	Grid 6 M4 0.061 A/m																	
Grid 7 M4 0.122 A/m	Grid 8 M4 0.096 A/m	Grid 9 M4 0.065 A/m																	
dB 0 -2.25 -4.51 -6.76 -9.02 -11.27																			

MEASUREMENT DATA WCDMA850, CHANNEL HIGH (846.6 MHz)

Date/Time: 2012-07-03 13:50:13 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 846.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:58:39 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 846.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA5 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 58.86 V/m; Power Drift = 0.01 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 50.97 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA5 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.06600 A/m; Power Drift = 0.07 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.08696 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 45.10 V/m</td><td>Grid 2 M4 51.55 V/m</td><td>Grid 3 M4 51.29 V/m</td></tr><tr><td>Grid 4 M4 43.13 V/m</td><td>Grid 5 M4 50.97 V/m</td><td>Grid 6 M4 50.73 V/m</td></tr><tr><td>Grid 7 M4 40.26 V/m</td><td>Grid 8 M4 48.95 V/m</td><td>Grid 9 M4 48.88 V/m</td></tr></table>	Grid 1 M4 45.10 V/m	Grid 2 M4 51.55 V/m	Grid 3 M4 51.29 V/m	Grid 4 M4 43.13 V/m	Grid 5 M4 50.97 V/m	Grid 6 M4 50.73 V/m	Grid 7 M4 40.26 V/m	Grid 8 M4 48.95 V/m	Grid 9 M4 48.88 V/m	<table><tr><td>Grid 1 M4 0.117 A/m</td><td>Grid 2 M4 0.087 A/m</td><td>Grid 3 M4 0.056 A/m</td></tr><tr><td>Grid 4 M4 0.106 A/m</td><td>Grid 5 M4 0.081 A/m</td><td>Grid 6 M4 0.055 A/m</td></tr><tr><td>Grid 7 M4 0.107 A/m</td><td>Grid 8 M4 0.085 A/m</td><td>Grid 9 M4 0.058 A/m</td></tr></table>	Grid 1 M4 0.117 A/m	Grid 2 M4 0.087 A/m	Grid 3 M4 0.056 A/m	Grid 4 M4 0.106 A/m	Grid 5 M4 0.081 A/m	Grid 6 M4 0.055 A/m	Grid 7 M4 0.107 A/m	Grid 8 M4 0.085 A/m	Grid 9 M4 0.058 A/m
Grid 1 M4 45.10 V/m	Grid 2 M4 51.55 V/m	Grid 3 M4 51.29 V/m																	
Grid 4 M4 43.13 V/m	Grid 5 M4 50.97 V/m	Grid 6 M4 50.73 V/m																	
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Grid 1 M4 0.117 A/m	Grid 2 M4 0.087 A/m	Grid 3 M4 0.056 A/m																	
Grid 4 M4 0.106 A/m	Grid 5 M4 0.081 A/m	Grid 6 M4 0.055 A/m																	
Grid 7 M4 0.107 A/m	Grid 8 M4 0.085 A/m	Grid 9 M4 0.058 A/m																	

dB

0

-1.85

-3.70

-5.55

-7.40

-9.25

MEASUREMENT DATA WCDMA1700/2100, CHANNEL LOW (1712.4MHz)

Date/Time: 2012-08-14 11:46:00 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1712.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-08-14 12:15:24 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1712.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)
Device E-Field measurement with ER probe/E Scan - WCDMA4 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 28.27 V/m; Power Drift = -0.06 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 41.10 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe/H Scan - WCDMA4 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.1140 A/m; Power Drift = 0.05 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.1088 A/m Near-field category: M4 (AWF 0 dB)

Grid 1 M4 39.17 V/m	Grid 2 M4 34.08 V/m	Grid 3 M4 29.91 V/m
Grid 4 M4 26.75 V/m	Grid 5 M4 33.15 V/m	Grid 6 M4 34.43 V/m
Grid 7 M4 25.03 V/m	Grid 8 M4 41.10 V/m	Grid 9 M4 41.48 V/m

Grid 1 M4 0.120 A/m	Grid 2 M4 0.115 A/m	Grid 3 M4 0.107 A/m
Grid 4 M4 0.104 A/m	Grid 5 M4 0.109 A/m	Grid 6 M4 0.107 A/m
Grid 7 M4 0.099 A/m	Grid 8 M4 0.099 A/m	Grid 9 M4 0.094 A/m

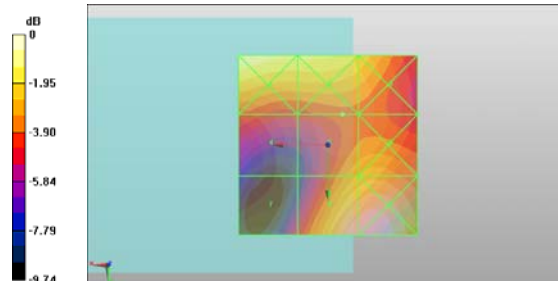


MEASUREMENT DATA WCDMA1700/2100, CHANNEL MIDDLE (1732.4MHz)

Date/Time: 2012-08-14 11:40:54 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1732.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-08-14 12:09:59 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1732.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)
Device E-Field measurement with ER probe/E Scan - WCDMA4 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 26.95 V/m; Power Drift = -0.09 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 39.61 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe/H Scan - WCDMA4 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.1130 A/m; Power Drift = -0.04 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.1061 A/m Near-field category: M4 (AWF 0 dB)

Grid 1 M4 37.57 V/m	Grid 2 M4 35.59 V/m	Grid 3 M4 32.06 V/m
Grid 4 M4 26.10 V/m	Grid 5 M4 30.22 V/m	Grid 6 M4 31.52 V/m
Grid 7 M4 22.31 V/m	Grid 8 M4 39.61 V/m	Grid 9 M4 40.25 V/m

Grid 1 M4 0.116 A/m	Grid 2 M4 0.108 A/m	Grid 3 M4 0.105 A/m
Grid 4 M4 0.099 A/m	Grid 5 M4 0.106 A/m	Grid 6 M4 0.105 A/m
Grid 7 M4 0.099 A/m	Grid 8 M4 0.098 A/m	Grid 9 M4 0.095 A/m



MEASUREMENT DATA WCDMA1700/2100, CHANNEL HIGH (1752.6MHz)

Date/Time: 2012-08-14 11:50:58 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1752.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469) Device E-Field measurement with ER probe/E Scan - WCDMA4 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 27.38 V/m; Power Drift = -0.12 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 37.65 V/m Near-field category: M4 (AWF 0 dB)	Date/Time: 2012-08-14 12:04:10 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870738/9 Communication System: UMTS-FDD (WCDMA) Frequency: 1752.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium Notes: Not Specified Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469) Device H-Field measurement with H3DV6 probe/H Scan - WCDMA4 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.1000 A/m; Power Drift = 0.00 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.09646 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 32.90 V/m</td><td>Grid 2 M4 34.13 V/m</td><td>Grid 3 M4 31.84 V/m</td></tr><tr><td>Grid 4 M4 22.50 V/m</td><td>Grid 5 M4 28.78 V/m</td><td>Grid 6 M4 29.97 V/m</td></tr><tr><td>Grid 7 M4 22.64 V/m</td><td>Grid 8 M4 37.65 V/m</td><td>Grid 9 M4 38.48 V/m</td></tr></table>	Grid 1 M4 32.90 V/m	Grid 2 M4 34.13 V/m	Grid 3 M4 31.84 V/m	Grid 4 M4 22.50 V/m	Grid 5 M4 28.78 V/m	Grid 6 M4 29.97 V/m	Grid 7 M4 22.64 V/m	Grid 8 M4 37.65 V/m	Grid 9 M4 38.48 V/m	<table><tr><td>Grid 1 M4 0.124 A/m</td><td>Grid 2 M4 0.107 A/m</td><td>Grid 3 M4 0.096 A/m</td></tr><tr><td>Grid 4 M4 0.093 A/m</td><td>Grid 5 M4 0.096 A/m</td><td>Grid 6 M4 0.096 A/m</td></tr><tr><td>Grid 7 M4 0.091 A/m</td><td>Grid 8 M4 0.083 A/m</td><td>Grid 9 M4 0.082 A/m</td></tr></table>	Grid 1 M4 0.124 A/m	Grid 2 M4 0.107 A/m	Grid 3 M4 0.096 A/m	Grid 4 M4 0.093 A/m	Grid 5 M4 0.096 A/m	Grid 6 M4 0.096 A/m	Grid 7 M4 0.091 A/m	Grid 8 M4 0.083 A/m	Grid 9 M4 0.082 A/m
Grid 1 M4 32.90 V/m	Grid 2 M4 34.13 V/m	Grid 3 M4 31.84 V/m																	
Grid 4 M4 22.50 V/m	Grid 5 M4 28.78 V/m	Grid 6 M4 29.97 V/m																	
Grid 7 M4 22.64 V/m	Grid 8 M4 37.65 V/m	Grid 9 M4 38.48 V/m																	
Grid 1 M4 0.124 A/m	Grid 2 M4 0.107 A/m	Grid 3 M4 0.096 A/m																	
Grid 4 M4 0.093 A/m	Grid 5 M4 0.096 A/m	Grid 6 M4 0.096 A/m																	
Grid 7 M4 0.091 A/m	Grid 8 M4 0.083 A/m	Grid 9 M4 0.082 A/m																	

dB

0

-1.69

-3.38

-5.08

-6.77

-8.46

MEASUREMENT DATA GSM1900, CHANNEL LOW (1850.2 MHz)

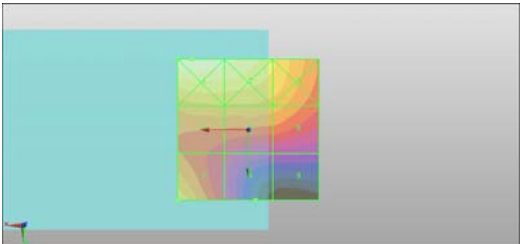
Date/Time: 2012-07-05 09:37:24 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1850.2 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 11:38:20 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1850.2 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF{1, 1, 1}; Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe/E Scan - GSM1900 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 19.71 V/m; Power Drift = 0.07 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 65.84 V/m Near-field category: M3 (AWF -5 dB)	Device H-Field measurement with H3DV6 probe/H Scan - GSM1900 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.05100 A/m; Power Drift = 0.03 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.1691 A/m Near-field category: M3 (AWF -5 dB)																		
<table><tr><td>Grid 1 M3 67.36 V/m</td><td>Grid 2 M3 74.07 V/m</td><td>Grid 3 M3 70.87 V/m</td></tr><tr><td>Grid 4 M3 52.46 V/m</td><td>Grid 5 M3 56.32 V/m</td><td>Grid 6 M3 52.90 V/m</td></tr><tr><td>Grid 7 M4 42.36 V/m</td><td>Grid 8 M3 62.15 V/m</td><td>Grid 9 M3 65.84 V/m</td></tr></table>	Grid 1 M3 67.36 V/m	Grid 2 M3 74.07 V/m	Grid 3 M3 70.87 V/m	Grid 4 M3 52.46 V/m	Grid 5 M3 56.32 V/m	Grid 6 M3 52.90 V/m	Grid 7 M4 42.36 V/m	Grid 8 M3 62.15 V/m	Grid 9 M3 65.84 V/m	<table><tr><td>Grid 1 M3 0.211 A/m</td><td>Grid 2 M3 0.177 A/m</td><td>Grid 3 M4 0.136 A/m</td></tr><tr><td>Grid 4 M3 0.143 A/m</td><td>Grid 5 M4 0.139 A/m</td><td>Grid 6 M4 0.140 A/m</td></tr><tr><td>Grid 7 M3 0.169 A/m</td><td>Grid 8 M3 0.164 A/m</td><td>Grid 9 M4 0.139 A/m</td></tr></table>	Grid 1 M3 0.211 A/m	Grid 2 M3 0.177 A/m	Grid 3 M4 0.136 A/m	Grid 4 M3 0.143 A/m	Grid 5 M4 0.139 A/m	Grid 6 M4 0.140 A/m	Grid 7 M3 0.169 A/m	Grid 8 M3 0.164 A/m	Grid 9 M4 0.139 A/m
Grid 1 M3 67.36 V/m	Grid 2 M3 74.07 V/m	Grid 3 M3 70.87 V/m																	
Grid 4 M3 52.46 V/m	Grid 5 M3 56.32 V/m	Grid 6 M3 52.90 V/m																	
Grid 7 M4 42.36 V/m	Grid 8 M3 62.15 V/m	Grid 9 M3 65.84 V/m																	
Grid 1 M3 0.211 A/m	Grid 2 M3 0.177 A/m	Grid 3 M4 0.136 A/m																	
Grid 4 M3 0.143 A/m	Grid 5 M4 0.139 A/m	Grid 6 M4 0.140 A/m																	
Grid 7 M3 0.169 A/m	Grid 8 M3 0.164 A/m	Grid 9 M4 0.139 A/m																	
dB 0 -1.17 -2.35 -3.52 -4.70 -5.87																			

MEASUREMENT DATA GSM1900, CHANNEL MIDDLE (1880 MHz)

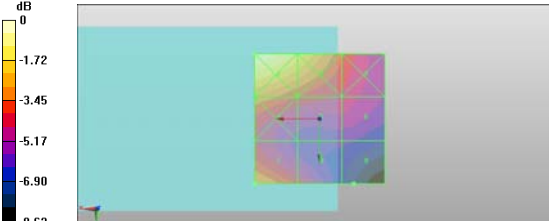
Date/Time: 2012-07-05 09:27:35 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1880 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF{1, 1, 1}; Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469) Device E-Field measurement with ER probe/E Scan - GSM1900 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 22.78 V/m; Power Drift = -0.08 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 59.09 V/m Near-field category: M3 (AWF -5 dB)	Date/Time: 2012-07-03 11:30:47 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1880 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469) Device H-Field measurement with H3DV6 probe/H Scan - GSM1900 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.04500 A/m; Power Drift = 0.04 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.1618 A/m Near-field category: M3 (AWF -5 dB)																		
<table><tr><td>Grid 1 M3 59.86 V/m</td><td>Grid 2 M3 70.50 V/m</td><td>Grid 3 M3 69.87 V/m</td></tr><tr><td>Grid 4 M4 46.80 V/m</td><td>Grid 5 M3 59.09 V/m</td><td>Grid 6 M3 58.91 V/m</td></tr><tr><td>Grid 7 M4 45.83 V/m</td><td>Grid 8 M3 54.41 V/m</td><td>Grid 9 M3 54.52 V/m</td></tr></table>	Grid 1 M3 59.86 V/m	Grid 2 M3 70.50 V/m	Grid 3 M3 69.87 V/m	Grid 4 M4 46.80 V/m	Grid 5 M3 59.09 V/m	Grid 6 M3 58.91 V/m	Grid 7 M4 45.83 V/m	Grid 8 M3 54.41 V/m	Grid 9 M3 54.52 V/m	<table><tr><td>Grid 1 M2 0.250 A/m</td><td>Grid 2 M3 0.222 A/m</td><td>Grid 3 M3 0.159 A/m</td></tr><tr><td>Grid 4 M3 0.177 A/m</td><td>Grid 5 M3 0.162 A/m</td><td>Grid 6 M4 0.135 A/m</td></tr><tr><td>Grid 7 M3 0.161 A/m</td><td>Grid 8 M4 0.130 A/m</td><td>Grid 9 M4 0.106 A/m</td></tr></table>	Grid 1 M2 0.250 A/m	Grid 2 M3 0.222 A/m	Grid 3 M3 0.159 A/m	Grid 4 M3 0.177 A/m	Grid 5 M3 0.162 A/m	Grid 6 M4 0.135 A/m	Grid 7 M3 0.161 A/m	Grid 8 M4 0.130 A/m	Grid 9 M4 0.106 A/m
Grid 1 M3 59.86 V/m	Grid 2 M3 70.50 V/m	Grid 3 M3 69.87 V/m																	
Grid 4 M4 46.80 V/m	Grid 5 M3 59.09 V/m	Grid 6 M3 58.91 V/m																	
Grid 7 M4 45.83 V/m	Grid 8 M3 54.41 V/m	Grid 9 M3 54.52 V/m																	
Grid 1 M2 0.250 A/m	Grid 2 M3 0.222 A/m	Grid 3 M3 0.159 A/m																	
Grid 4 M3 0.177 A/m	Grid 5 M3 0.162 A/m	Grid 6 M4 0.135 A/m																	
Grid 7 M3 0.161 A/m	Grid 8 M4 0.130 A/m	Grid 9 M4 0.106 A/m																	



MEASUREMENT DATA GSM1900, CHANNEL HIGH (1909.8 MHz)

Date/Time: 2012-07-05 09:43:01 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1909.8 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 11:43:47 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870752/0 Communication System: GSM-FDD (TDMA, GMSK) Frequency: 1909.8 MHz; Duty Cycle: 1:8.31764 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe/E Scan - GSM1900 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 20.73 V/m; Power Drift = -0.01 dB PMR calibrated. Calibrated PMF = 2.948 is applied. E-field emissions = 64.87 V/m Near-field category: M3 (AWF -5 dB)	Device H-Field measurement with H3DV6 probe/H Scan - GSM1900 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.05300 A/m; Power Drift = -0.03 dB PMR calibrated. Calibrated PMF = 2.948 is applied. H-field emissions = 0.1812 A/m Near-field category: M3 (AWF -5 dB)																		
<table><tr><td>Grid 1 M3 65.96 V/m</td><td>Grid 2 M3 62.94 V/m</td><td>Grid 3 M3 62.51 V/m</td></tr><tr><td>Grid 4 M4 43.36 V/m</td><td>Grid 5 M3 59.90 V/m</td><td>Grid 6 M3 59.71 V/m</td></tr><tr><td>Grid 7 M3 56.62 V/m</td><td>Grid 8 M3 64.87 V/m</td><td>Grid 9 M3 62.90 V/m</td></tr></table>	Grid 1 M3 65.96 V/m	Grid 2 M3 62.94 V/m	Grid 3 M3 62.51 V/m	Grid 4 M4 43.36 V/m	Grid 5 M3 59.90 V/m	Grid 6 M3 59.71 V/m	Grid 7 M3 56.62 V/m	Grid 8 M3 64.87 V/m	Grid 9 M3 62.90 V/m	<table><tr><td>Grid 1 M3 0.223 A/m</td><td>Grid 2 M3 0.215 A/m</td><td>Grid 3 M3 0.186 A/m</td></tr><tr><td>Grid 4 M3 0.171 A/m</td><td>Grid 5 M3 0.171 A/m</td><td>Grid 6 M3 0.166 A/m</td></tr><tr><td>Grid 7 M3 0.181 A/m</td><td>Grid 8 M4 0.134 A/m</td><td>Grid 9 M4 0.118 A/m</td></tr></table>	Grid 1 M3 0.223 A/m	Grid 2 M3 0.215 A/m	Grid 3 M3 0.186 A/m	Grid 4 M3 0.171 A/m	Grid 5 M3 0.171 A/m	Grid 6 M3 0.166 A/m	Grid 7 M3 0.181 A/m	Grid 8 M4 0.134 A/m	Grid 9 M4 0.118 A/m
Grid 1 M3 65.96 V/m	Grid 2 M3 62.94 V/m	Grid 3 M3 62.51 V/m																	
Grid 4 M4 43.36 V/m	Grid 5 M3 59.90 V/m	Grid 6 M3 59.71 V/m																	
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Grid 1 M3 0.223 A/m	Grid 2 M3 0.215 A/m	Grid 3 M3 0.186 A/m																	
Grid 4 M3 0.171 A/m	Grid 5 M3 0.171 A/m	Grid 6 M3 0.166 A/m																	
Grid 7 M3 0.181 A/m	Grid 8 M4 0.134 A/m	Grid 9 M4 0.118 A/m																	
dB 0 -1.72 -3.44 -5.17 -6.89 -8.61 																			

MEASUREMENT DATA WCDMA1900, CHANNEL LOW (1852.4MHZ)

Date/Time: 2012-07-03 13:24:09 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1852.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:34:45 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1852.4 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF(1, 1, 1); Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA2 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 33.27 V/m; Power Drift = 0.02 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 32.66 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA2 - Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.07600 A/m; Power Drift = -0.02 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.09440 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 33.24 V/m</td><td>Grid 2 M4 37.73 V/m</td><td>Grid 3 M4 36.73 V/m</td></tr><tr><td>Grid 4 M4 25.55 V/m</td><td>Grid 5 M4 30.30 V/m</td><td>Grid 6 M4 29.81 V/m</td></tr><tr><td>Grid 7 M4 24.34 V/m</td><td>Grid 8 M4 31.94 V/m</td><td>Grid 9 M4 32.66 V/m</td></tr></table>	Grid 1 M4 33.24 V/m	Grid 2 M4 37.73 V/m	Grid 3 M4 36.73 V/m	Grid 4 M4 25.55 V/m	Grid 5 M4 30.30 V/m	Grid 6 M4 29.81 V/m	Grid 7 M4 24.34 V/m	Grid 8 M4 31.94 V/m	Grid 9 M4 32.66 V/m	<table><tr><td>Grid 1 M4 0.129 A/m</td><td>Grid 2 M4 0.110 A/m</td><td>Grid 3 M4 0.082 A/m</td></tr><tr><td>Grid 4 M4 0.092 A/m</td><td>Grid 5 M4 0.081 A/m</td><td>Grid 6 M4 0.075 A/m</td></tr><tr><td>Grid 7 M4 0.094 A/m</td><td>Grid 8 M4 0.079 A/m</td><td>Grid 9 M4 0.063 A/m</td></tr></table>	Grid 1 M4 0.129 A/m	Grid 2 M4 0.110 A/m	Grid 3 M4 0.082 A/m	Grid 4 M4 0.092 A/m	Grid 5 M4 0.081 A/m	Grid 6 M4 0.075 A/m	Grid 7 M4 0.094 A/m	Grid 8 M4 0.079 A/m	Grid 9 M4 0.063 A/m
Grid 1 M4 33.24 V/m	Grid 2 M4 37.73 V/m	Grid 3 M4 36.73 V/m																	
Grid 4 M4 25.55 V/m	Grid 5 M4 30.30 V/m	Grid 6 M4 29.81 V/m																	
Grid 7 M4 24.34 V/m	Grid 8 M4 31.94 V/m	Grid 9 M4 32.66 V/m																	
Grid 1 M4 0.129 A/m	Grid 2 M4 0.110 A/m	Grid 3 M4 0.082 A/m																	
Grid 4 M4 0.092 A/m	Grid 5 M4 0.081 A/m	Grid 6 M4 0.075 A/m																	
Grid 7 M4 0.094 A/m	Grid 8 M4 0.079 A/m	Grid 9 M4 0.063 A/m																	
0 -1.72 -3.45 -5.17 -6.90 -8.62 																			

MEASUREMENT DATA WCDMA1900, CHANNEL MIDDLE (1880MHz)

Date/Time: 2012-07-03 13:18:36 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1880 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:23:02 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1880 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF{1, 1, 1}; Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA2 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 30.42 V/m; Power Drift = -0.09 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 31.42 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA2 - Middle/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.07800 A/m; Power Drift = -0.08 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.09519 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 32.67 V/m</td><td>Grid 2 M4 34.88 V/m</td><td>Grid 3 M4 34.45 V/m</td></tr><tr><td>Grid 4 M4 21.70 V/m</td><td>Grid 5 M4 28.44 V/m</td><td>Grid 6 M4 28.44 V/m</td></tr><tr><td>Grid 7 M4 25.07 V/m</td><td>Grid 8 M4 31.42 V/m</td><td>Grid 9 M4 31.15 V/m</td></tr></table>	Grid 1 M4 32.67 V/m	Grid 2 M4 34.88 V/m	Grid 3 M4 34.45 V/m	Grid 4 M4 21.70 V/m	Grid 5 M4 28.44 V/m	Grid 6 M4 28.44 V/m	Grid 7 M4 25.07 V/m	Grid 8 M4 31.42 V/m	Grid 9 M4 31.15 V/m	<table><tr><td>Grid 1 M4 0.130 A/m</td><td>Grid 2 M4 0.115 A/m</td><td>Grid 3 M4 0.084 A/m</td></tr><tr><td>Grid 4 M4 0.095 A/m</td><td>Grid 5 M4 0.090 A/m</td><td>Grid 6 M4 0.076 A/m</td></tr><tr><td>Grid 7 M4 0.095 A/m</td><td>Grid 8 M4 0.077 A/m</td><td>Grid 9 M4 0.060 A/m</td></tr></table>	Grid 1 M4 0.130 A/m	Grid 2 M4 0.115 A/m	Grid 3 M4 0.084 A/m	Grid 4 M4 0.095 A/m	Grid 5 M4 0.090 A/m	Grid 6 M4 0.076 A/m	Grid 7 M4 0.095 A/m	Grid 8 M4 0.077 A/m	Grid 9 M4 0.060 A/m
Grid 1 M4 32.67 V/m	Grid 2 M4 34.88 V/m	Grid 3 M4 34.45 V/m																	
Grid 4 M4 21.70 V/m	Grid 5 M4 28.44 V/m	Grid 6 M4 28.44 V/m																	
Grid 7 M4 25.07 V/m	Grid 8 M4 31.42 V/m	Grid 9 M4 31.15 V/m																	
Grid 1 M4 0.130 A/m	Grid 2 M4 0.115 A/m	Grid 3 M4 0.084 A/m																	
Grid 4 M4 0.095 A/m	Grid 5 M4 0.090 A/m	Grid 6 M4 0.076 A/m																	
Grid 7 M4 0.095 A/m	Grid 8 M4 0.077 A/m	Grid 9 M4 0.060 A/m																	
0 -1.85 -3.70 -5.55 -7.40 -9.25																			

MEASUREMENT DATA WCDMA1900, CHANNEL HIGH (1907.6MHz)

Date/Time: 2012-07-03 13:29:41 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1907.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section	Date/Time: 2012-07-03 12:40:06 Test Laboratory: TCC Nokia Type: RM-820; Serial: 004402/13/870734/8 Communication System: UMTS-FDD (WCDMA) Frequency: 1907.6 MHz; Duty Cycle: 1:2.18776 Medium: Air; Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section																		
DASY Configuration: - Probe: ER3DV6 - SN2333 - ConvF{1, 1, 1}; Calibrated: 2012-04-19; - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)	DASY Configuration: - Probe: H3DV6 - SN6053 - ; Calibrated: 2012-04-18 - Sensor-Surface: (Fix Surface) - Electronics: DAE4 Sn1316; Calibrated: 2012-02-15 - Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; - Measurement SW: DASY52, Version 52.8 (0); SEMCAD X Version 14.6.5 (6469)																		
Device E-Field measurement with ER probe, WCDMA/E Scan - WCDMA2 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 26.78 V/m; Power Drift = -0.09 dB PMR calibrated. Calibrated PMF = 1.020 is applied. E-field emissions = 34.79 V/m Near-field category: M4 (AWF 0 dB)	Device H-Field measurement with H3DV6 probe, WCDMA/H Scan - WCDMA2 - High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.08700 A/m; Power Drift = -0.06 dB PMR calibrated. Calibrated PMF = 1.020 is applied. H-field emissions = 0.09457 A/m Near-field category: M4 (AWF 0 dB)																		
<table><tr><td>Grid 1 M4 35.46 V/m</td><td>Grid 2 M4 33.50 V/m</td><td>Grid 3 M4 32.44 V/m</td></tr><tr><td>Grid 4 M4 23.15 V/m</td><td>Grid 5 M4 29.77 V/m</td><td>Grid 6 M4 29.99 V/m</td></tr><tr><td>Grid 7 M4 26.76 V/m</td><td>Grid 8 M4 34.79 V/m</td><td>Grid 9 M4 34.57 V/m</td></tr></table>	Grid 1 M4 35.46 V/m	Grid 2 M4 33.50 V/m	Grid 3 M4 32.44 V/m	Grid 4 M4 23.15 V/m	Grid 5 M4 29.77 V/m	Grid 6 M4 29.99 V/m	Grid 7 M4 26.76 V/m	Grid 8 M4 34.79 V/m	Grid 9 M4 34.57 V/m	<table><tr><td>Grid 1 M4 0.110 A/m</td><td>Grid 2 M4 0.105 A/m</td><td>Grid 3 M4 0.093 A/m</td></tr><tr><td>Grid 4 M4 0.086 A/m</td><td>Grid 5 M4 0.089 A/m</td><td>Grid 6 M4 0.088 A/m</td></tr><tr><td>Grid 7 M4 0.095 A/m</td><td>Grid 8 M4 0.076 A/m</td><td>Grid 9 M4 0.069 A/m</td></tr></table>	Grid 1 M4 0.110 A/m	Grid 2 M4 0.105 A/m	Grid 3 M4 0.093 A/m	Grid 4 M4 0.086 A/m	Grid 5 M4 0.089 A/m	Grid 6 M4 0.088 A/m	Grid 7 M4 0.095 A/m	Grid 8 M4 0.076 A/m	Grid 9 M4 0.069 A/m
Grid 1 M4 35.46 V/m	Grid 2 M4 33.50 V/m	Grid 3 M4 32.44 V/m																	
Grid 4 M4 23.15 V/m	Grid 5 M4 29.77 V/m	Grid 6 M4 29.99 V/m																	
Grid 7 M4 26.76 V/m	Grid 8 M4 34.79 V/m	Grid 9 M4 34.57 V/m																	
Grid 1 M4 0.110 A/m	Grid 2 M4 0.105 A/m	Grid 3 M4 0.093 A/m																	
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Grid 7 M4 0.095 A/m	Grid 8 M4 0.076 A/m	Grid 9 M4 0.069 A/m																	
</																			

APPENDIX C: RELEVANT PAGES FROM PROBE CALIBRATION REPORT(S)



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Nokia Salo TCC**

Certificate No: **ER3-2333_Apr12**

CALIBRATION CERTIFICATE

Object **ER3DV6 - SN:2333**

Calibration procedure(s) **QA CAL-02.v6, QA CAL-25.v4**
Calibration procedure for E-field probes optimized for close near field
evaluations in air

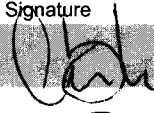
Calibration date: **April 19, 2012**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature $(22 \pm 3)^{\circ}\text{C}$ and humidity $< 70\%$.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	29-Mar-12 (No. 217-01508)	Apr-13
Power sensor E4412A	MY41498087	29-Mar-12 (No. 217-01508)	Apr-13
Reference 3 dB Attenuator	SN: S5054 (3c)	27-Mar-12 (No. 217-01531)	Apr-13
Reference 20 dB Attenuator	SN: S5086 (20b)	27-Mar-12 (No. 217-01529)	Apr-13
Reference 30 dB Attenuator	SN: S5129 (30b)	27-Mar-12 (No. 217-01532)	Apr-13
Reference Probe ER3DV6	SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by:	Name Claudio Leubler	Function Laboratory Technician	Signature 
Approved by:	Name Katja Pokovic	Function Technical Manager	Signature 

Issued: April 25, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2333

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm ($\mu\text{V}/(\text{V}/\text{m})^2$)	1.44	1.50	1.44	$\pm 10.1 \%$
DCP (mV) ^B	101.8	100.5	104.2	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
0	CW	0.00	X	0.00	0.00	1.00	247.4	$\pm 3.5 \%$
			Y	0.00	0.00	1.00	188.2	
			Z	0.00	0.00	1.00	232.0	
10011	UMTS-FDD (WCDMA)	3.40	X	3.63	67.1	19.2	143.3	$\pm 0.7 \%$
			Y	3.28	64.8	18.0	111.6	
			Z	3.56	66.7	18.6	135.6	
10021	GSM-FDD (TDMA, GMSK)	9.40	X	5.28	81.6	22.0	124.8	$\pm 2.2 \%$
			Y	7.35	87.8	24.7	136.4	
			Z	8.28	84.9	22.8	130.2	
10039	CDMA2000 (1xRTT, RC1)	4.57	X	4.58	66.5	19.2	137.2	$\pm 0.7 \%$
			Y	4.42	65.7	18.8	109.9	
			Z	4.45	66.5	18.9	127.1	
10081	CDMA2000 (1xRTT, RC3)	3.96	X	3.79	66.0	18.8	136.7	$\pm 0.5 \%$
			Y	3.65	65.0	18.4	109.8	
			Z	3.80	66.4	18.7	127.6	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor $k=2$, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter; uncertainty not required.

^E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.



Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Nokia Salo TCC**

Certificate No: **H3-6053_Apr12**

CALIBRATION CERTIFICATE

Object **H3DV6 - SN:6053**

Calibration procedure(s) **QA CAL-03.v6, QA CAL-25.v4**
Calibration procedure for H-field probes optimized for close near field evaluations in air

Calibration date: **April 18, 2012**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	29-Mar-12 (No. 217-01508)	Apr-13
Power sensor E4412A	MY41498087	29-Mar-12 (No. 217-01508)	Apr-13
Reference 3 dB Attenuator	SN: S5054 (3c)	27-Mar-12 (No. 217-01531)	Apr-13
Reference 20 dB Attenuator	SN: S5086 (20b)	27-Mar-12 (No. 217-01529)	Apr-13
Reference 30 dB Attenuator	SN: S5129 (30b)	27-Mar-12 (No. 217-01532)	Apr-13
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by:	Name Claudio Leubler	Function Laboratory Technician	Signature
Approved by:	Katja Pokovic	Technical Manager	

Issued: April 26, 2012

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DASY/EASY - Parameters of Probe: H3DV6 - SN:6053

Basic Calibration Parameters

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (A/m / $\sqrt{\text{mV}}$)	a0	2.79E-003	2.62E-003	2.97E-003	$\pm 5.1 \%$
Norm (A/m / $\sqrt{\text{mV}}$)	a1	-1.52E-004	-2.23E-004	-4.24E-004	$\pm 5.1 \%$
Norm (A/m / $\sqrt{\text{mV}}$)	a2	-7.97E-006	8.36E-005	8.20E-005	$\pm 5.1 \%$
DCP (mV) ^B		91.2	91.6	91.7	

Modulation Calibration Parameters

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc ^E (k=2)
0	CW	0.00	X	0.00	0.00	1.00	235.7	$\pm 3.0 \%$
			Y	0.00	0.00	1.00	264.2	
			Z	0.00	0.00	1.00	206.9	
10011	UMTS-FDD (WCDMA)	3.40	X	3.03	61.9	16.2	74.2	$\pm 0.5 \%$
			Y	3.23	63.1	16.9	86.4	
			Z	3.30	63.6	17.2	90.7	
10021	GSM-FDD (TDMA, GMSK)	9.40	X	9.99	71.6	23.2	80.1	$\pm 1.9 \%$
			Y	10.13	70.6	22.8	69.2	
			Z	9.76	70.6	22.8	69.8	
10039	CDMA2000 (1xRTT, RC1)	4.57	X	4.74	63.6	17.3	80.4	$\pm 1.2 \%$
			Y	4.98	64.6	17.9	90.6	
			Z	5.07	65.0	18.0	96.9	
10081	CDMA2000 (1xRTT, RC3)	3.96	X	3.76	62.8	16.8	77.4	$\pm 0.7 \%$
			Y	3.93	63.8	17.4	86.3	
			Z	3.91	63.6	17.2	92.0	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor $k=2$, which for a normal distribution corresponds to a coverage probability of approximately 95%.

^B Numerical linearization parameter: uncertainty not required.

^E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

APPENDIX D: RELEVANT PAGES FROM DIPOLE VALIDATION KIT REPORT(S)



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 Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Nokia Salo TCC**

Certificate No: **CD835V3-1004_Sep10**

CALIBRATION CERTIFICATE

Object **CD835V3 - SN: 1004**

Calibration procedure(s) **QA CAL-20.v5**
Calibration procedure for dipoles in air

Calibration date: **September 15, 2010**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
 All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-09 (No. 217-01086)	Oct-10
Power sensor HP 8481A	US37292783	06-Oct-09 (No. 217-01086)	Oct-10
Probe ER3DV6	SN: 2336	30-Dec-09 (No. ER3-2336_Dec09)	Dec-10
Probe H3DV6	SN: 6065	30-Dec-09 (No. H3-6065_Dec09)	Dec-10
DAE4	SN: 781	22-Jan-10 (No. DAE4-781_Jan10)	Jan-11
Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

Calibrated by: **Claudio Leubler** **Laboratory Technician** **Signature**

Approved by: **Fin Bomholt** **Technical Director**

Issued: September 16, 2010

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

3.3.3 DASY4 H-field Result

Date/Time: 14.09.2010 10:52:58

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1004_H_100914_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1004

Communication System: CW; Communication System Band: CD835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 22.01.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.2 Build 0, Version 52.2.0 (163)
- Postprocessing SW: SEMCAD X, V14.2 Build 2, Version 14.2.2 (1685)

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.464 A/m

Probe Modulation Factor = 1

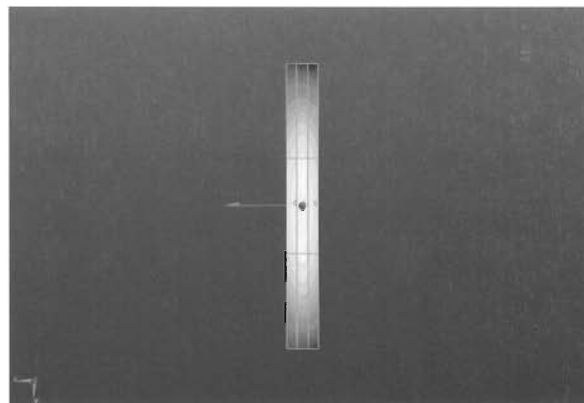
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.495 A/m; Power Drift = -0.032 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.383 M4	Grid 2 0.403 M4	Grid 3 0.383 M4
Grid 4 0.441 M4	Grid 5 0.464 M4	Grid 6 0.439 M4
Grid 7 0.396 M4	Grid 8 0.418 M4	Grid 9 0.393 M4



0 dB = 0.464A/m



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 Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: **SCS 108**

Client **Nokia Salo TCC**

Certificate No: **CD1880V3-1003_Sep10**

CALIBRATION CERTIFICATE

Object **CD1880V3 - SN: 1003**

Calibration procedure(s) **QA CAL-20.v5**
Calibration procedure for dipoles in air

Calibration date: **September 15, 2010**

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).
 All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter EPM-442A	GB37480704	06-Oct-09 (No. 217-01086)	Oct-10
Power sensor HP 8481A	US37292783	06-Oct-09 (No. 217-01086)	Oct-10
Probe ER3DV6	SN: 2336	30-Dec-09 (No. ER3-2336_Dec09)	Dec-10
Probe H3DV6	SN: 6065	30-Dec-09 (No. H3-6065_Dec09)	Dec-10
DAE4	SN: 781	22-Jan-10 (No. DAE4-781_Jan10)	Jan-11

Secondary Standards	ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482H	SN: 3318A09450	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-09)	In house check: Oct-10
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-09)	In house check: Oct-10
RF generator E4433B	MY 41000675	03-Nov-04 (in house check Oct-09)	In house check: Oct-11

	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	

Approved by:	Fin Bornholt	Technical Director
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Issued: September 16, 2010

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3.3.2 DASY4 H-Field Result

Date/Time: 14.09.2010 14:40:22

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1003_E_100914_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1003

Communication System: CW; Communication System Band: CD1880 (1880.0 MHz); Frequency: 1880 MHz;

Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: H3DV6 - SN6065; ; Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 22.01.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.2 Build 0, Version 52.2.0 (163)
- Postprocessing SW: SEMCAD X, V14.2 Build 2, Version 14.2.2 (1685)

Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.458 A/m

Probe Modulation Factor = 1

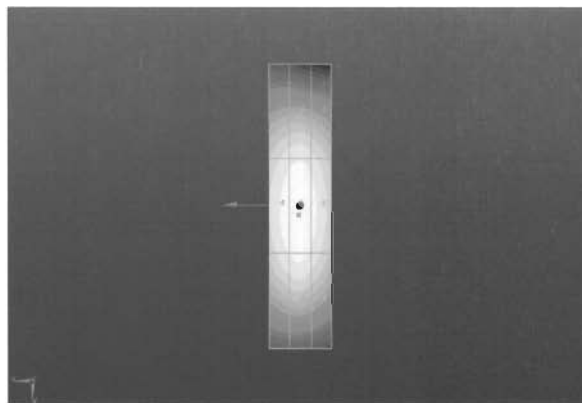
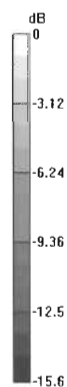
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.486 A/m; Power Drift = -0.017 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1 0.386 M2	Grid 2 0.402 M2	Grid 3 0.381 M2
Grid 4 0.441 M2	Grid 5 0.458 M2	Grid 6 0.431 M2
Grid 7 0.409 M2	Grid 8 0.426 M2	Grid 9 0.397 M2



0 dB = 0.458A/m

3.3.3 DASY4 E-Field Result

Date/Time: 15.09.2010 13:51:38

Test Laboratory: SPEAG Lab2

HAC_RF_CD1880_1003_E_100914_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1003

Communication System: CW; Communication System Band: CD1880 (1880.0 MHz); Frequency: 1880 MHz;

Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 22.01.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.2 Build 0, Version 52.2.0 (163)
- Postprocessing SW: SEMCAD X, V14.2 Build 2, Version 14.2.2 (1685)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 135.1 V/m

Probe Modulation Factor = 1

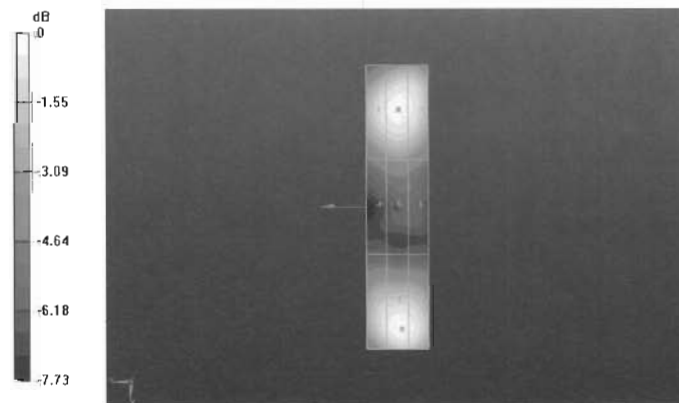
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 151.2 V/m; Power Drift = -0.00243 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1 127.2 M2	Grid 2 132.4 M2	Grid 3 131.0 M2
Grid 4 90.1 M3	Grid 5 93.3 M3	Grid 6 91 M3
Grid 7 126.6 M2	Grid 8 135.1 M2	Grid 9 133.8 M2



0 dB = 135.1V/m

3.3.2 DASY4 E-field Result

Date/Time: 15.09.2010 16:00:54

Test Laboratory: SPEAG Lab2

HAC RF_CD835_1004_E_100914_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1004

Communication System: CW; Communication System Band: CD835 (835.0 MHz); Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

- Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 30.12.2009
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 22.01.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.2 Build 0, Version 52.2.0 (163)
- Postprocessing SW: SEMCAD X, V14.2 Build 2, Version 14.2.2 (1685)

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 168.5 V/m

Probe Modulation Factor = 1

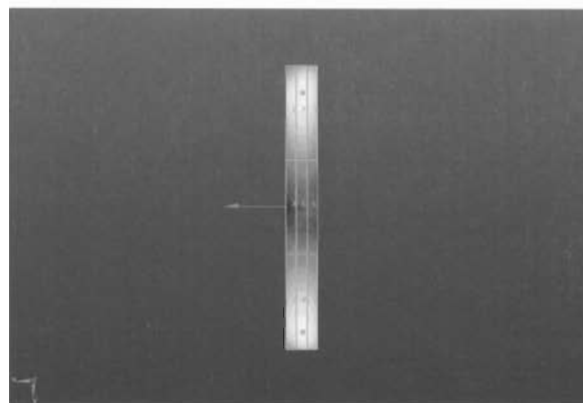
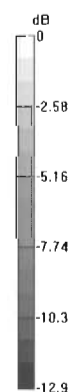
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 108.8 V/m; Power Drift = 0.00473 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1 162.6 M4	Grid 2 168.5 M4	Grid 3 165.2 M4
Grid 4 87.8 M4	Grid 5 91.1 M4	Grid 6 89.2 M4
Grid 7 160.2 M4	Grid 8 167.7 M4	Grid 9 164.6 M4



0 dB = 168.5V/m